Electronic Supplementary Information

Photovoltaic poly (rod-coil) polymers based on benzodithiophene-

centred A-D-A type conjugated segments and dicarboxylate-linked

alkyl non-conjugated segments

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Contents

Fig. S1	¹ H NMR spectrum of compound 1 .
Fig. S2	¹ H NMR spectrum of compound 2 .
Fig. S3	¹ H NMR spectrum of compound 3 .
Fig. S4	¹ H NMR spectrum of compound 4 .
Fig. S5	¹ H NMR spectrum of compound 5 .
Fig. S6	¹ H NMR spectrum of compound 6 .
Fig. S7	¹ H NMR spectrum of compound 7 .
Fig. S8	MALDI-TOF mass spectrum of compound 7.
Fig. S9	TGA curves of P1 , P2 , P3 , P4 and P5 .
Fig. S10	DSC curves of P1 , P2 , P3 , P4 and P5 .
Fig. S11	The SCLC fitting curves of P1, P2, P3, P4 and P5 measured with a device
	structure of ITO/PEDTO:PSS/active layer/Au.
Table S1	Device optimization for the OSCs based on P1.
Table S2	Device optimization for the OSCs based on P2.
Table S3	Device optimization for the OSCs based on P3.
Table S4	Device optimization for the OSCs based on P4.
Table S5	Device optimization for the OSCs based on P5.







Fig. S2 ¹H NMR spectrum of compound **2** (CDCl₃).







Fig. S4 ¹H NMR spectrum of compound **4** (CDCl₃).







Fig. S6 ¹H NMR spectrum of compound **6** (CDCl₃).





	P	its-		
720001 E5[c] 20 Nov 2014 10.16 Cal. LSH1000-4000 20 Nov 2014 10.1 ech Axima Performance 2.8.4 20081127: Mode Reflectron, Power: 69, B 792 mV[sum= 2377 mV] Profiles 6-8 Smooth Av 5 -Baseline 80	14 Blanked, P.I	Ext. @ 1	500 (bin	80x 2MS
and dome for the the	1088.4			
	1090.4			
	1089.4			
	1087.4			
0 694.5 739.5 779.8 855.4 934.7 984.6 4	1093.4	1153.8	1206.0	1260 4
700 800 900 1000 m/z	1100		1200	

Fig. S8 MALDI-TOF MS of compound 7.



Fig. S9 TGA curves of P1, P2, P3, P4 and P5.



Fig. S10 DSC curves of P1, P2, P3, P4 and P5.



Fig. S11 In*J*–In*V* data in dark of hole-only devices based on **P1**, **P2**, **P3**, **P4** and **P5** in blending with PC₆₁BM and their SCLC fitting curves.

Coluont		Spin-coating speed	Annealing	V _{oc}	J _{sc}	FF	PCE ^a
Solvent	P1/PC ₆₁ Bivi	(rpm)	(°C)	(∨)	(mA cm ⁻²)	(%)	(%)
	1/1	1000		0.61	1.82	26.9	0.30 (0.30)
		700		0.62	1.67	26.6	0.28 (0.26)
CD	1/1 F	1000	100	0.64	2.33	28.1	0.42 (0.41)
СВ	1/1.5	1500	100	0.72	2.21	29.1	0.46 (0.43)
		2000		0.66	1.87	27.4	0.34 (0.32)
	1/2	1000		0.72	1.59	28.3	0.33 (0.31)
	1 /1 F	1500	60	0.59	2.02	28.6	0.34 (0.33)
			80	0.65	2.03	28.2	0.37 (0.36)
o-DCB	1/1.5		100	0.73	2.19	29.8	0.47 (0.44)
			120	0.65	2.25	28.5	0.42 (0.41)
	1/2	1000		0.69	1.92	28.7	0.38 (0.37)
		1000	100	0.70	1.41	26.5	0.26 (0.25)
CF	1/1.5	1500	100	0.70	2.02	29.9	0.42 (0.40)
		2500		0.68	2.04	26.9	0.37 (0.35)

Table S1Device parameters of **P1**/PC61BM-based solar cells under different conditions.

 $^{\it a}$ average value of PCE in the parenthesis.

Table S2	Device para	Spin-coating speed (rpm) Annealing (°C) Voc (V) Jsc (mA cm ⁻²) FF PCE ° 1/1 1000 0.68 1.43 26.5 0.26 (0.25) 1/1 1000 0.72 1.68 27.2 0.33 (0.32) 100 0.75 2.04 27.3 0.42 (0.36) 100 0.75 1.69 28.3 0.32 (0.31) 1/1.5 1500 100 0.76 1.99 33.8 0.51 (0.50) 1/1.5 140 0.43 1.81 27.0 0.26 (0.25)								
Columnt		Spin-coating speed	Annealing	V _{oc}	J _{sc}	FF	PCE ^a			
Solvent	PZ/PC ₆₁ BIVI	(rpm)	(°C)	(∨)	(mA cm ⁻²)	(%)	(%)			
	1/1	1000		0.68	1.43	26.5	0.26 (0.25)			
		700	100	0.72	1.68	27.2	0.33 (0.32)			
		1000		0.75	2.04	27.3	0.42 (0.36)			
			60	0.66	1.69	28.3	0.32 (0.31)			
			80	0.72	1.80	28.5	0.37 (0.35)			
	1/1 F	1500	100	0.76	1.99	33.8	0.51 (0.50)			
	1/1.5		120	0.55	1.62	28.8	0.26 (0.25)			
0-DCB			140	0.43	1.81	27.0	0.21 (0.18)			
		2000		0.70	1.26	32.8	0.29 (0.27)			
		2500		0.58	0.95	33.5	0.18 (0.16)			
		1000		0.69	1.92	28.7	0.38 (0.37)			
	1/2			0.66	2.05	28.0	0.38 (0.36)			
	1/2			0.66	1.93	27.7	0.36 (0.33)			
	1/2.5	1000	100	0.59	1.77	27.7	0.29 (0.26)			
СВ	1/2			0.72	1.55	29.1	0.32 (0.30)			
Toluene	1/2			0.77	1.30	27.7	0.30 (0.28)			
		1000		0.72	2.05	28.7	0.42 (0.41)			
CF	1/1.5	1500		0.73	2.12	28.2	0.44 (0.41)			
		2500		0.66	1.92	28.1	0.36 (0.33)			

Table S2	Device parameters	of P2/PC61BM-base	d solar cells unde	r different conditions

^a average value of PCE in the parenthesis.

Solvent		Spin-coating speed	Annealing	V _{oc}	J _{sc}	FF	PCE ^a
Solvent	P3 /PC ₆₁ DIVI	(rpm)	(°C)	(∨)	(mA cm ⁻²)	(%)	(%)
		1000		0.76	1.54	28.9	0.34 (0.33)
CF		1500		0.74	1.49	30.8	0.34 (0.28)
		2500	100	0.76	1.61	27.4	0.33 (0.30)
	1/1.5	1000	100	0.71	1.32	30.4	0.28 (0.26)
СВ		1500		0.73	1.66	30.0	0.36 (0.30)
		2500		0.70	1.49	28.3	0.30 (0.27)
			RT	0.58	1.38	26.8	0.21 (0.21)
o-DCB		1500	100	0.74	2.15	28.8	0.46 (0.42)
			120	0.62	1.26	27.6	0.22 (0.20)

Table S3Device parameters of $P3/PC_{61}BM$ -based solar cells under different conditions.

^{*a*} average value of PCE in the parenthesis.

Table S4	Device	parameters of	f P4 /PC	₆₁ BM-based	solar o	cells under	r different	conditions.
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Solvent		Spin-coating speed	Annealing	V _{oc}	J _{sc}	FF	PCE ^a
Solvent	F4/FC61DIVI	(rpm)	(°C)	(V)	(mA cm ⁻²)	(%)	(%)
	1/1.5	500		0.67	2.22	29.5	0.44 (0.40)
o-DCB		1500	RT	0.67	2.23	33.6	0.51 (0.43)
		2500		0.79	2.77	31.6	0.69 (0.64)

^a average value of PCE in the parenthesis.

Solvent CF CB		Spin-coating speed	Annealing	V _{oc}	J _{sc}	FF	PCE ^a
Solvent	P5/PC ₆₁ BIN	(rpm)	(°C)	(∨)	(mA cm ⁻²)	(%)	(%)
	3/1			0.91	1.65	27.4	0.41 (0.38)
	2/1		RT	0.84	2.56	31.4	0.68 (0.52)
		1500		0.84	2.40	35.7	0.72 (0.60)
	1/1	1500	100	0.87	2.32	33.5	0.68 (0.66)
			120	0.87	1.88	32.0	0.53 (0.51)
CF.				0.85	2.87	34.2	0.84 (0.80)
CF	1/1.5	1000		0.85	2.64	46.5	1.05 (0.93)
		2000		0.83	2.67	49.4	1.09 (1.00)
		2500		0.88	2.53	41.3	0.92 (0.76)
		1500		0.87	2.12	44.2	0.82 (0.72)
		2500		0.87	2.15	50.7	0.99 (0.89)
		4000	RT	0.84	2.18	52.3	0.96 (0.72)
		1000		0.82	2.84	43.4	1.01 (0.99)
СВ	1/1.5	1500		0.82	2.85	41.8	0.98 (0.92)
		2500		0.67	2.60	45.1	0.79 (0.70)
		1000		0.80	2.35	38.5	0.72 (0.52)
o-DCB	1/1.5	1500		0.83	2.32	45.8	0.88 (0.82)
		2500		0.87	1.74	33.8	0.51 (0.49)

Table S5	Device parar	neters c	of P5 /P0	C ₆₁ BM∙	based	d solar ce	ells under d	lifferent condi	tions.	

^a average value of PCE in the parenthesis.